

Supporting Information

Porous CuBi₂O₄ Photocathodes with Rationally Engineered Morphology and Composition towards Photoelectrochemical Water Splitting

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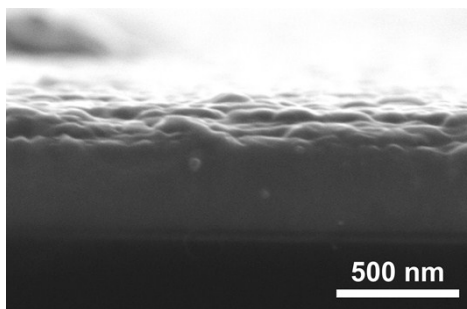


Figure S1. Cross sectional SEM image of the CuBi₂O₄ film by spin coating 0.15 M precursor solution with no F-108 (CBO).

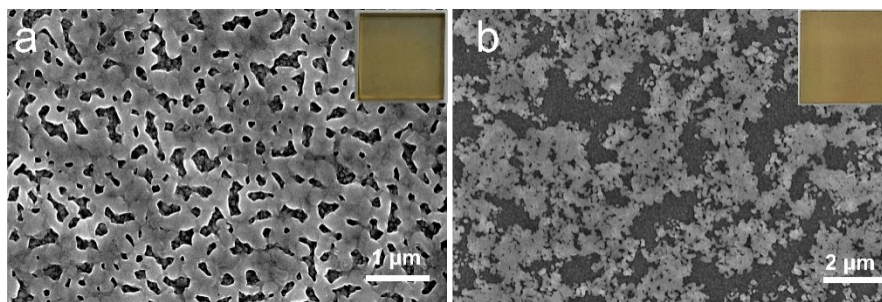


Figure S2. SEM images of CuBi_2O_4 film by spin coating 0.15 M precursor solution with (a) 0.05 mg/ml F-108 (CBO-F-108-1) and (b) 0.25 mg/ml F-108 (CBO-F-108-1).

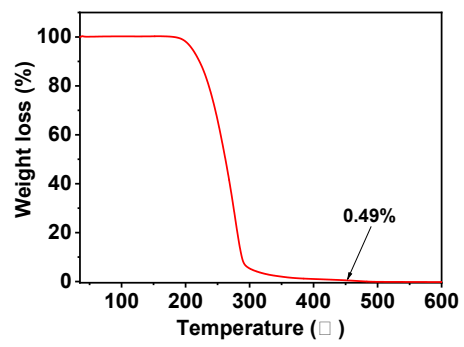


Figure S3. TG curve of F-108.

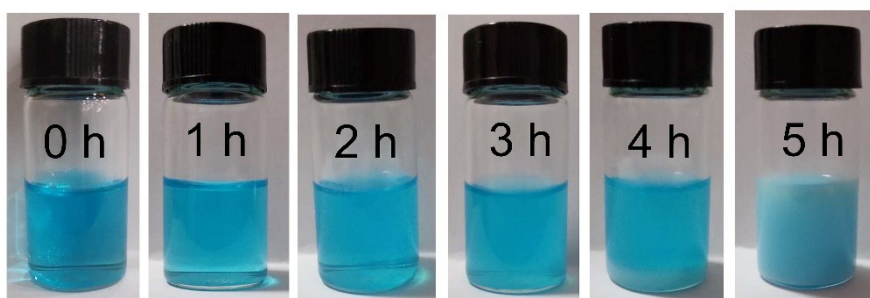


Figure S4. Photographs of precursor solution with ethanol and acetic acid (2:1 by volume) aging for different time of periods.

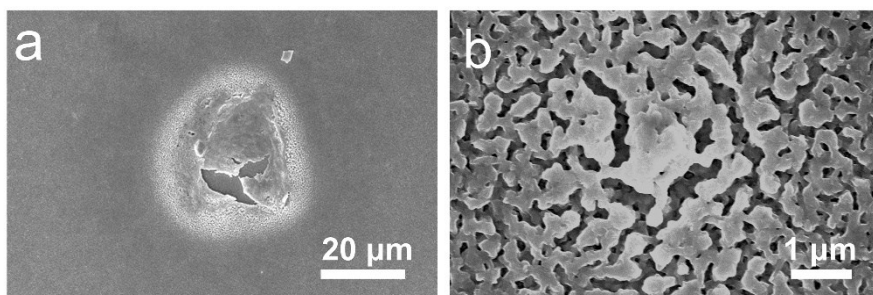


Figure S5. SEM images of uneven CuBi_2O_4 films by spin coating hydrolyzed precursor solution.

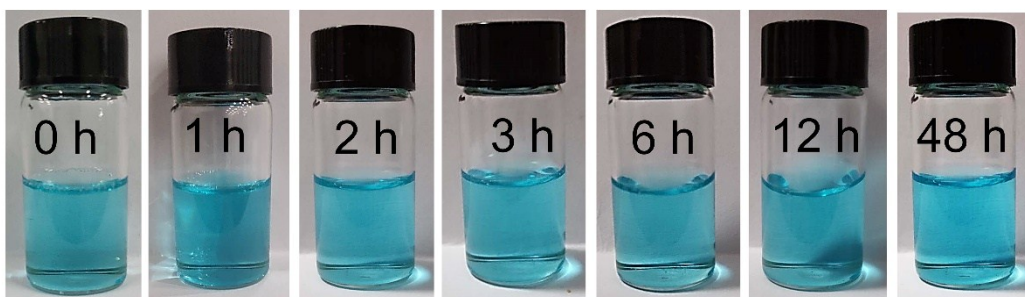


Figure S6. Photographs of precursor solution with 35% ethylene glycol by volume aging for different time of periods.

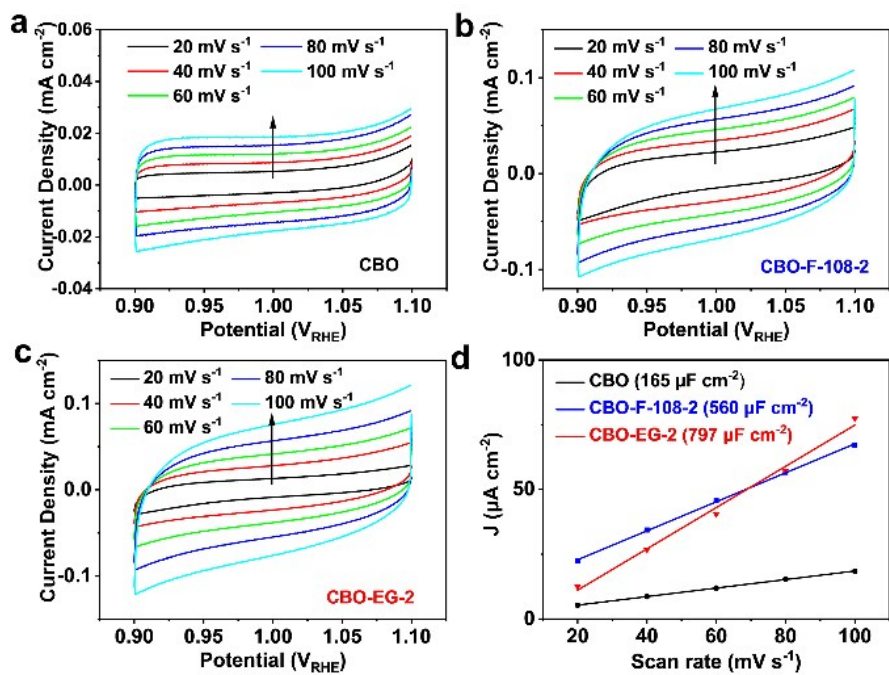


Figure S7. Cyclic voltammetry curves of (a) CBO (no F-108, no EG), (b) CBO-F-108-2 and (c) CBO-EG-2 photocathodes at various scan rates (20-100 mV s^{-1}). (d) Estimate of double layer capacitance to reflect the electrochemical active surface area.

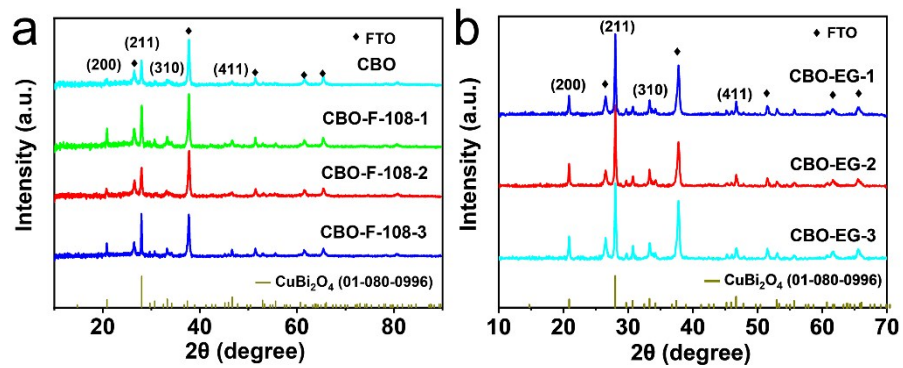


Figure S8. (a) XRD patterns of CBO (no F-108 and no EG), CBO-F-108-1, CBO-F-108-2 and CBO-F-108-3. (b) XRD patterns of CBO-EG-1, CBO-EG-2 and CBO-EG-3.

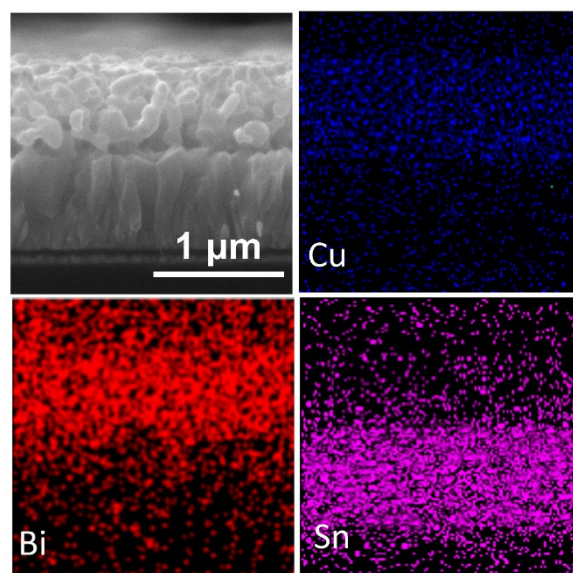


Figure S9. Cross-sectional SEM-EDS mapping of CBO-EG-2 film.

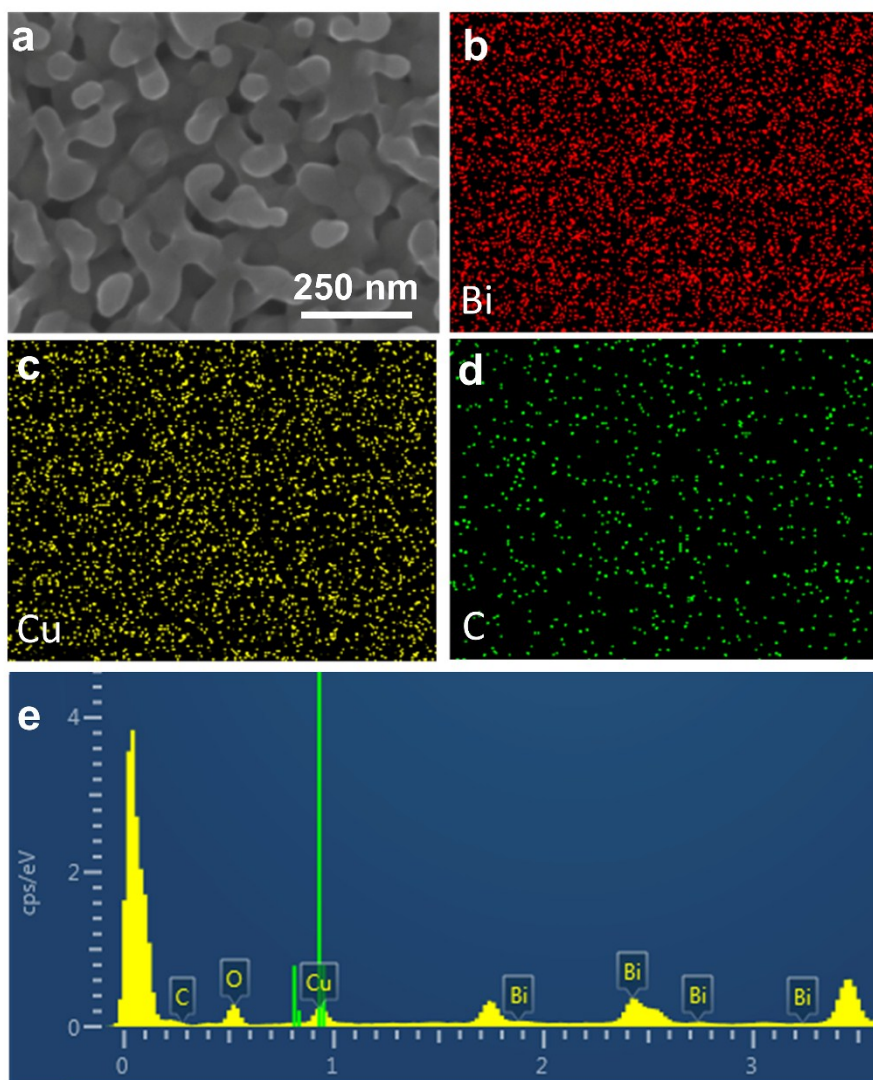


Figure S10. (a)-(d) SEM-EDS mappings of CBO-EG-2 calcining at 450 °C for 1h. (e) Element content distribution map of the CuBi_2O_4 film.

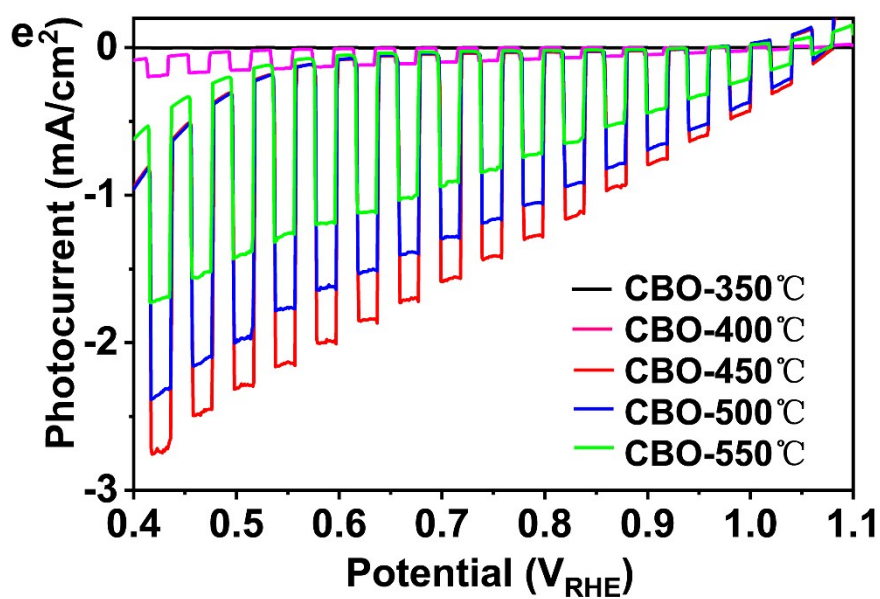
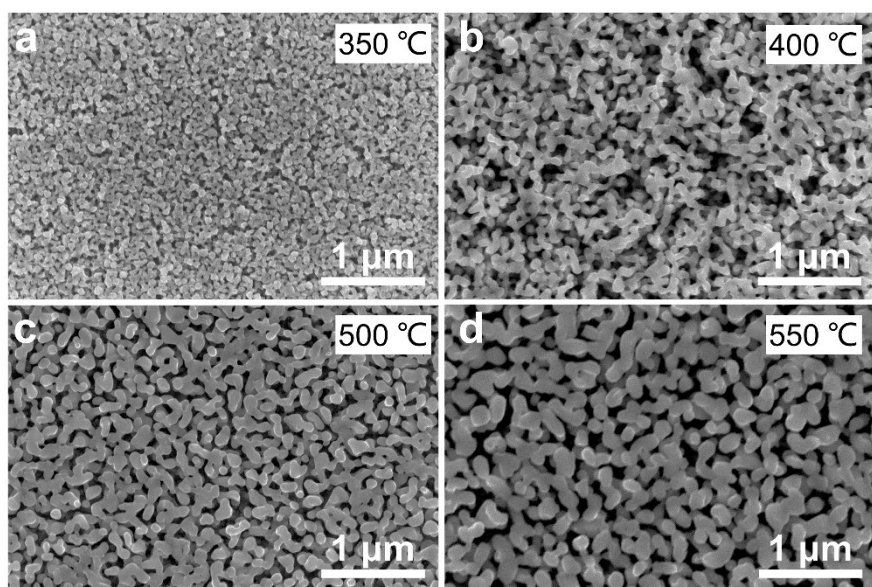


Figure S11. SEM images of nanoporous CuBi_2O_4 films calcined at different temperatures: (a) 350 °C, (b) 400 °C, (c) 500 °C, and (d) 550 °C. (e) Chopped LSV scans of these samples performed in 0.3 M K_2SO_4 and 0.2 M phosphate buffer (pH 6.65) with H_2O_2 back AM1.5 illumination.

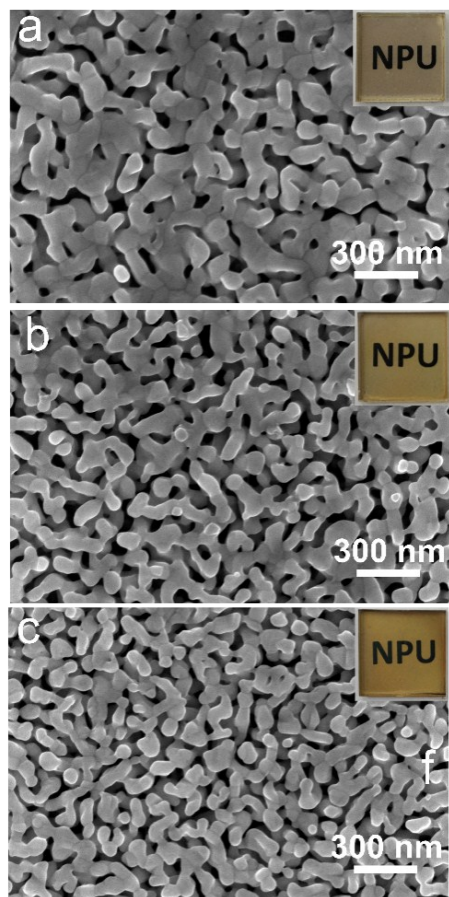


Figure S12. SEM images of nanoporous CuBi_2O_4 films with different thicknesses: (a) 150 nm, (b) 300 nm, and (c) 400 nm.

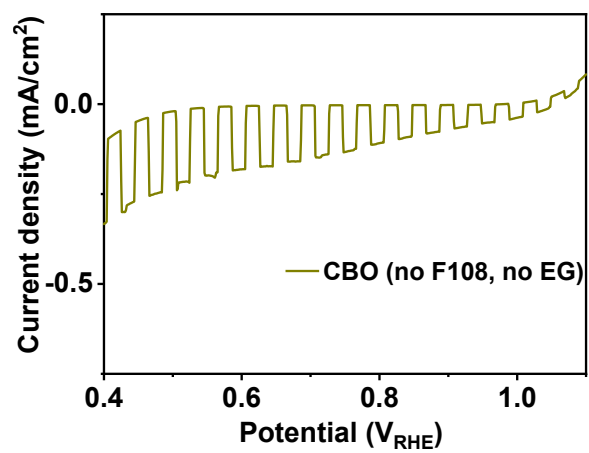


Figure S13. Chopped (light/dark) LSV scans of CBO (no F-108, no EG) performed in 0.3 M K₂SO₄ and 0.2 M phosphate buffer (pH 6.65) with H₂O₂ back AM1.5 illumination.

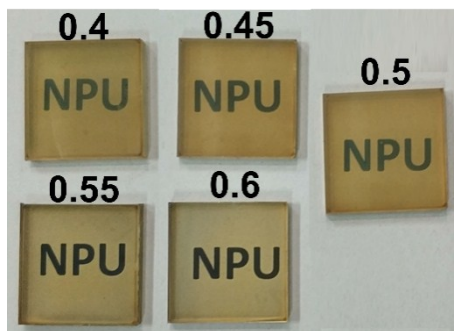


Figure S14. Digital photographs of CBO films with various Cu/Bi ratios.

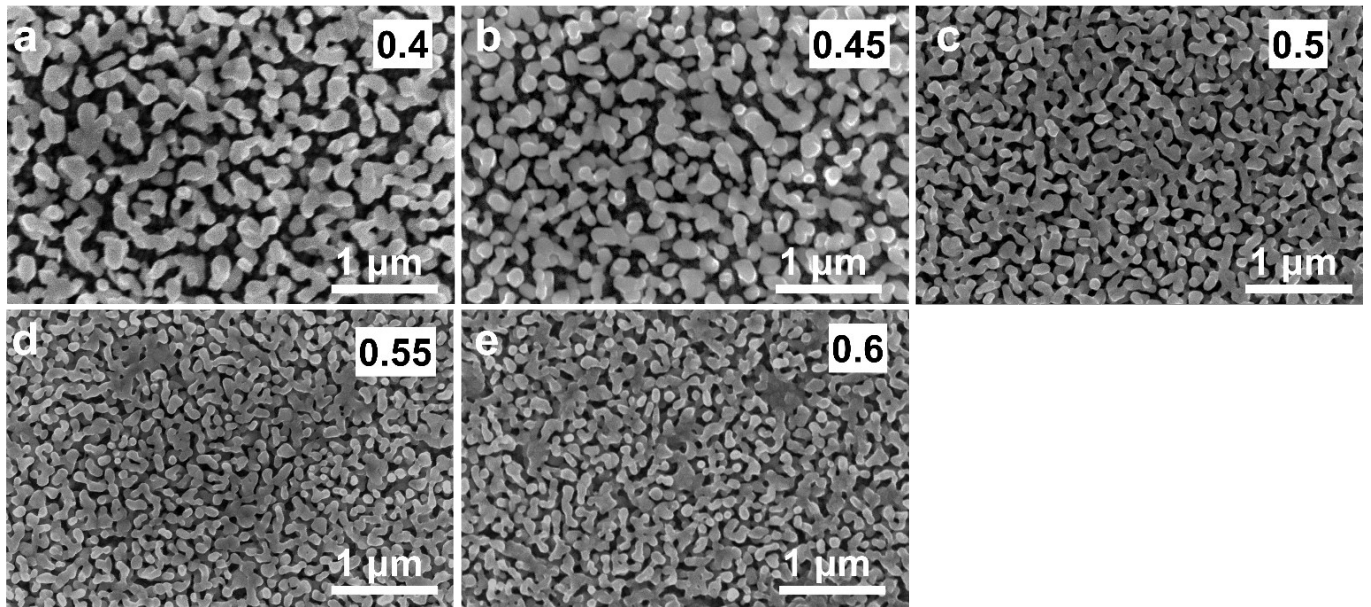


Figure S15. SEM images of CBO films with various Cu/Bi ratios.

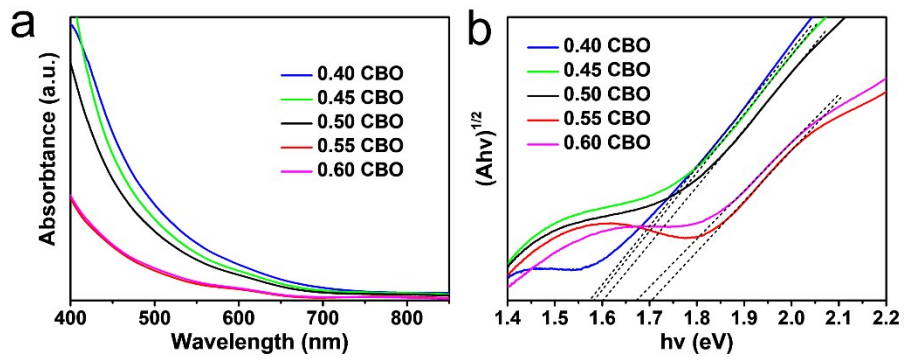


Figure S16. (a) UV/Vis absorbance spectra of CBO films with various Cu/Bi ratios. (b) Tauc plots of CBO films converted from the UV/Vis absorbance spectra. Bandgap of CBO films are 1.57, 1.58, 1.60, 1.70, and 1.67 eV for 0.40 CBO, 0.45 CBO, 0.50 CBO, 0.55 CBO, and 0.60 CBO samples.

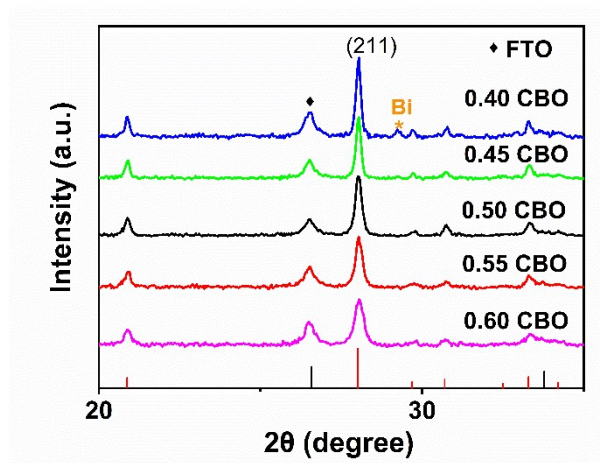


Figure S17. XRD patterns of the fabricated photocathodes.

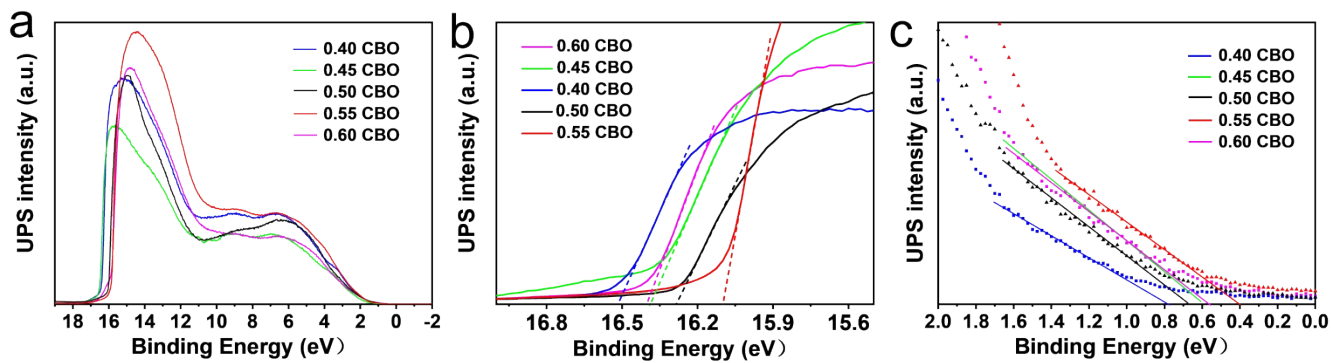


Figure S18. (a) UPS cutoff spectra for different CBO films; Magnified UPS spectra used to estimate (b) work function and (c) VBM.

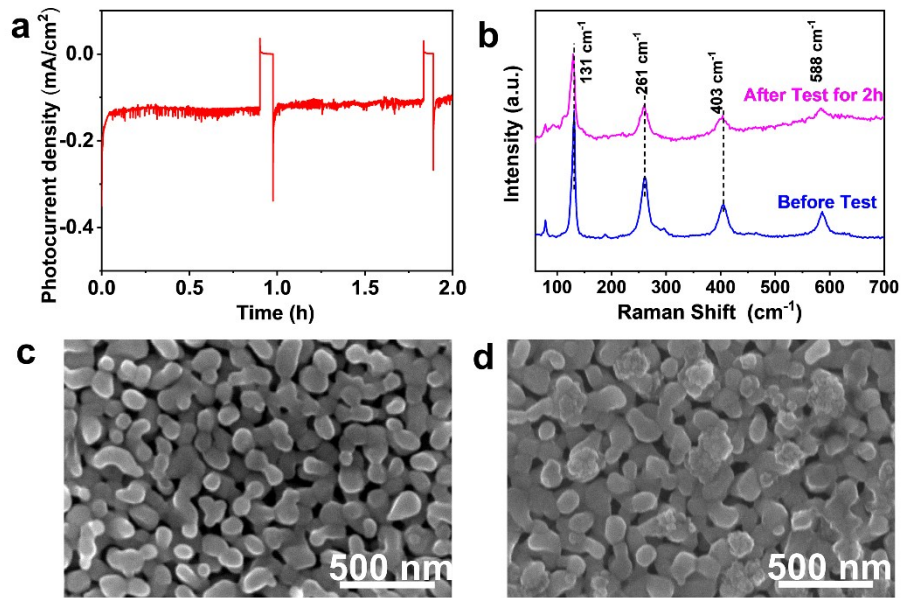


Figure S19. (a) Constant potential measurements for 0.55 CBO photocathode at 0.6 V vs RHE in 0.3 M K₂SO₄ and 0.2 M phosphate buffer (pH 6.65), the on and off photocurrent at around 1.0 h and 2.0 h was due to the chopped illumination of the light source. (b) Raman spectra of 0.55 CBO photocathode before and after stability test. SEM images of 0.55 CBO photocathode (c) before test and (d) after test.

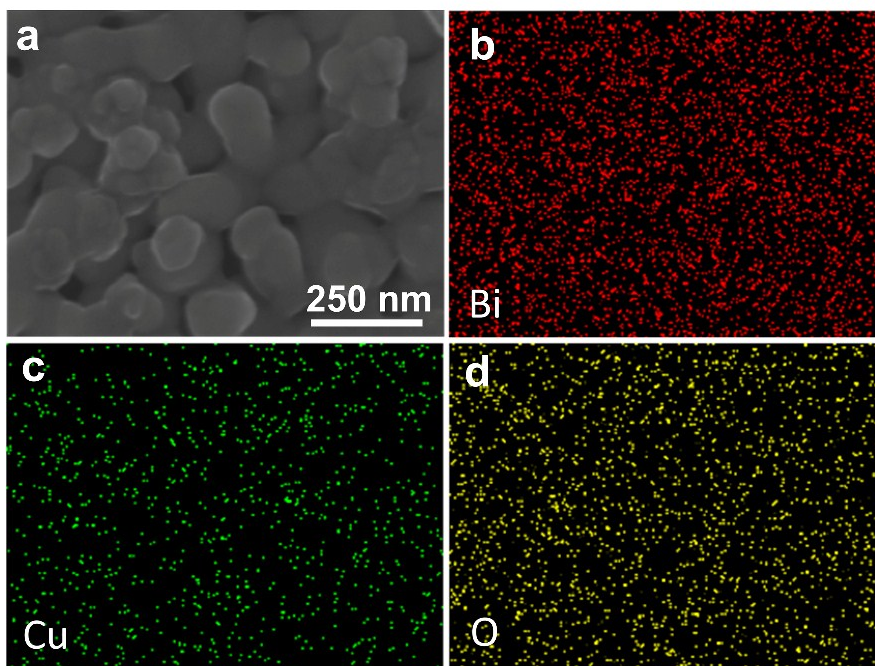


Figure S20. SEM-EDS mapping of 0.55 CBO photocathode after testing for two hours at 0.6 V vs RHE in 0.3 M K_2SO_4 and 0.2 M phosphate buffer (pH 6.65).

Table S1. Process parameters of CuBi₂O₄ films with different thicknesses.

Thickness	150 nm	300 nm	400 nm
Precursor concentration (Cu)	0.12 M	0.18 M	0.225 M
Solvent	acetic acid : ethanol : ethylene glycol 1:1:1	acetic acid : ethanol : ethylene glycol 1:1:1	acetic acid : ethanol : ethylene glycol 1:1:1
F-108	0.1 g/ml	0.2 g/ml	0.225 g/ml
Rotating speed	2000r,10s; 4500r,40s	2000r,10s; 3500r,40s	2000r,10s; 3000r,40s
Preheating temperature	150 °C	150 °C	125 °C
Calcination temperature	450 °C	450 °C	450 °C

Table S2. Series resistance (R_s) and charge transfer resistance (R_{ct}) of different CuBi_2O_4 samples.

Sample (Cu/Bi ratio)	R_s (ohm)	R_{ct} (ohm)
0.4 CBO	78	15000
0.45 CBO	80	5437
0.5 CBO	77	6132
0.55 CBO	84	4980
0.6 CBO	1980	9440

Table S3. Flat-band potential (ϕ_{fb}) and acceptor density (N_A) of different Cu/Bi ratio CBO samples calculated by Mott-Schottky plot.

Sample (Cu/Bi ratio)	ϕ_{fb} (V_{RHE})	N_A (cm^{-3})
0.4 CBO	1.31	1.7×10^{18}
0.45 CBO	1.35	2.3×10^{18}
0.5 CBO	1.31	2.4×10^{18}
0.55 CBO	1.26	4.2×10^{18}
0.6 CBO	1.31	2.5×10^{18}

Table S4. Bandgap and positions (distance from the vacuum level) of VBM (E_v), CBM (E_c), and Fermi level (E_f) of CBO samples determined by UV/Vis spectroscopy and UPS.

Sample (Cu/Bi ratio)	E_g (eV)	E_v (eV)	E_c (eV)	E_f (eV)
0.4 CBO	1.57	5.47	3.90	4.69
0.45 CBO	1.58	5.42	3.84	4.82
0.5 CBO	1.60	5.60	4.00	4.92
0.55 CBO	1.67	5.51	3.84	5.11
0.6 CBO	1.70	5.36	3.66	4.81

Table S5. Experimental results summary for the recently published CuBi₂O₄ photocathodes for PEC water splitting.

CuBi ₂ O ₄ Photocathode	Photocurrent @ Potential (mA/cm ²)	Electrolyte	Light Source	Preparation Technique	References
CuO/ CuBi ₂ O ₄ /Pt	0.7 @ 0 V NHE	0.3M K ₂ SO ₄ pH 6.8	>420nm	Drop-casting	S1
FTO/Au/ CuBi ₂ O ₄ /Pt	-1.24 @ 0.1V vs RHE	0.1 M Na ₂ SO ₄ pH 6.8	AM1.5G Simulator	Cathodically electrochemical deposition	S2
Ag- CuBi ₂ O ₄ /Pt	1.0@0.6 V RHE	0.1 M NaOH (pH 12.8) saturated with O ₂	AM1.5G Simulator	Electrodeposition	S3
CuBi ₂ O ₄	2.0 @0.6 V RHE	0.3 M K ₂ SO ₄ and 0.2 M phosphate buffer, with H ₂ O ₂	AM1.5G Simulator	Spray pyrolysis	S4
CuBi ₂ O ₄	0.02 @ -0.25V vs Ag/AgCl	0.3 M Na ₂ SO ₄	100 mW/cm ²	Hydrothermal	S5
CuBi ₂ O ₄ /Pt	0.5 @ 0.4 V RHE	0.3 M K ₂ SO ₄ and 0.2 M phosphate buffer	AM1.5G Simulator	Drop-casting	S6
CuBi ₂ O ₄	0.07@ 0.6V vs RHE	0.1 M Na ₂ SO ₄ adjusted pH 10.8	Xe lamp, >420nm	Electrochemical Synthesis	S7
CuBi ₂ O ₄ /CuO	0.28 @ -0.4V vs Ag/AgCl	0.1 M Na ₂ SO ₄ pH 6.8	Xe lamp, 400 W	Spray-coating	S8
CuBi ₂ O ₄	0.03 @ -0.4V vs Ag/AgCl	0.1 M Na ₂ SO ₄ pH 6.8	500W Xe lamp,>420nm filter	Electrodeposition	S9
CuBi ₂ O ₄	0.12@ -0.3V vs Ag/AgCl	0.5 M Na ₂ SO ₄	AM 1.5, 100 mW cm ⁻²	Flux-mediated one- pot solution process	S10
Gradient CuBi ₂ O ₄	2.5 @ 0.6V vs RHE (With H ₂ O ₂)	0.3 M K ₂ SO ₄ and 0.2 M phosphate buffer (H ₂ O ₂)	AM1.5G Simulator	Spray pyrolysis	S11
Textured CuBi ₂ O ₄	0.72 @ -0.6V vs Ag/AgCl	0.1 M Na ₂ SO ₄ pH 6.8	AM1.5G Simulator	Vacuum Drop- casting	S12
Cu:NiO/CuBi ₂ O ₄	2.83 @ 0.6V vs RHE	0.3 M K ₂ SO ₄ and 0.2 M phosphate buffer (H ₂ O ₂)	AM1.5G Simulator	Spray pyrolysis	S13
CuBi ₂ O ₄ (Bi:Cu=1.5)	1.17 @ 0.58 V vs RHE	0.1 M KHCO ₃ with 0.1 M Na ₂ S ₂ O ₈ pH 8.2	AM1.5G Simulator	spin coating	S14
CuBi ₂ O ₄	2.66 @ 0.6V vs RHE (With H ₂ O ₂)	0.3 M K ₂ SO ₄ and 0.2 M phosphate buffer (H ₂ O ₂)	AM1.5G Simulator	spin coating	This work

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